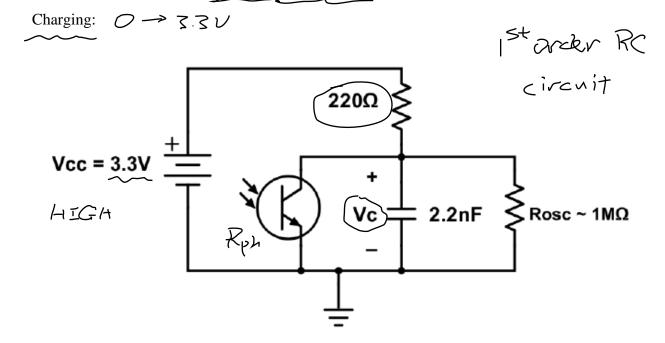


FIGURE 3-1: High level understanding of the ECE3 class project

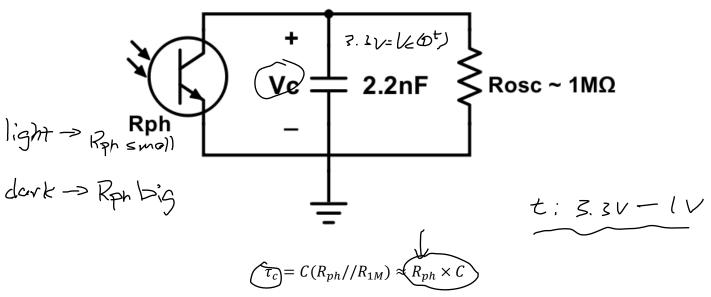
Working Mechanism of the phototransistor circuitry:

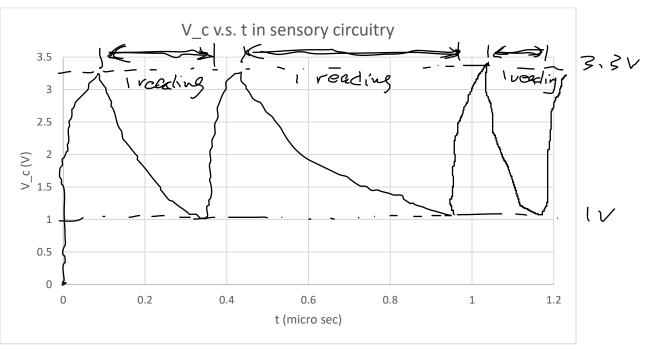


$$\underbrace{\tau_c} = C(R_{220} / / R_{ph} / / R_{1M}) \approx \underbrace{2200} \times C$$

very short time (20.4 ms)

Discharging: $3.3V \rightarrow 0V$

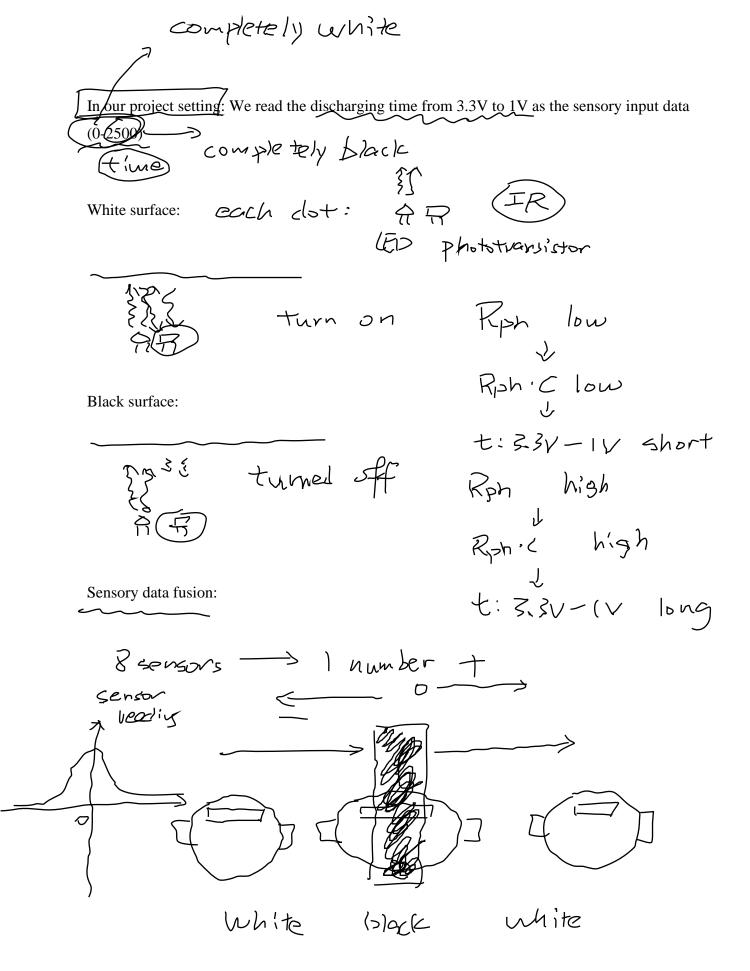




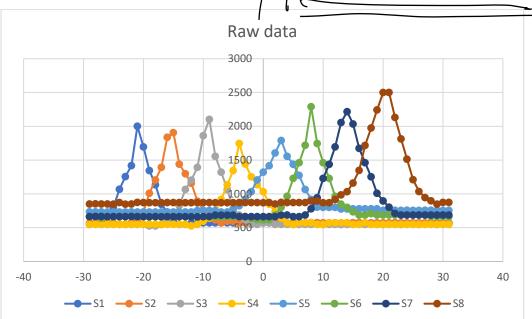
when seusor see black Total time needed to wait for each read? (~2ms per reading)

> Worst case Scenario

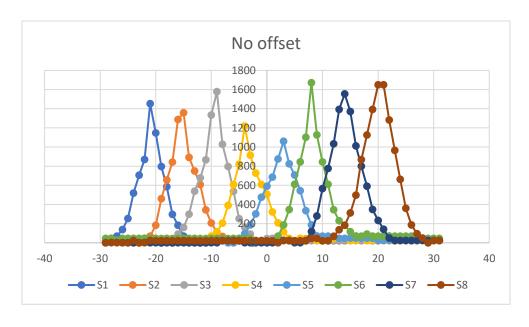
I nour project Sampling vate (~ 150 Samples /s/

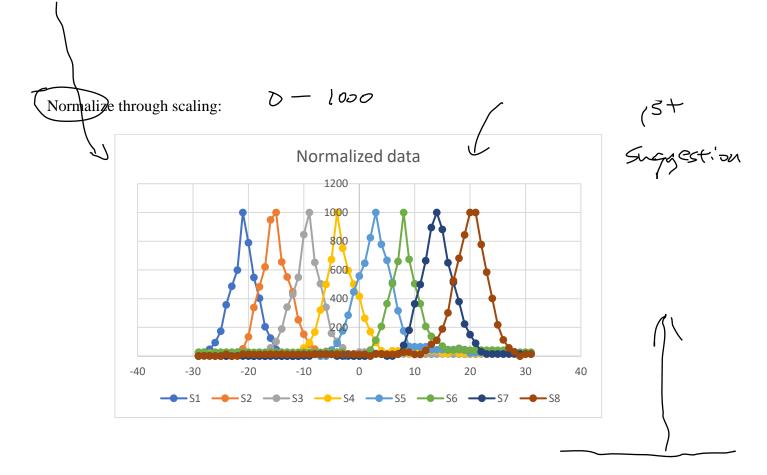




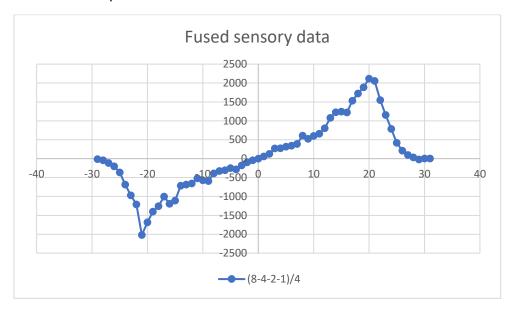


Kill the offsets:





Sensor fusion: (Skip)



"Pseudocode" of our project: Void setup () { pinMet - --ECE3_In(+L); roig (oob() (DRed Raw Data from 8 sensors e -> 8 numbers from 0-2500 (2) Hard code the clara colibration Kill offset Siale -> 3 nm bers 0 - 1000 (clean data) Suggestion 3 Charge motor Speed according to sensor in puts